

DALLAS SEMICONDUCTOR IME

Goal = 300 ppm

Flow	Part	IME Results											
		4Q03			3Q03			2Q03			1Q03		
		Total	Fails	PPM	Total	Fails	PPM	Total	Fails	PPM	Total	Fails	PPM
D6L	DS7864B				3277	3	915				4027	3	745
D6S	DS2118M	3332	0	0									
D6W	DS1849	2696	1	371									
D6W	DS1859				3089	1	324						
D6W	DS2438	3390	1	295									
D8N	DS17885										7190	70	9736
D8S	DS1834	2534	0	0							4463	0	0
E6H	DS21354				3372	3	890						
E6P	DS2120	3080	0	0									
E6RH	DS5240	3096	16	5168									
E6S	DS2118M	2530	2	791	23834	11	462				3286	0	0
E6S	DS2119M	9590	1	104									
E6W	DS1849	3322	1	301									

Dallas fab qualified processes only.

Dates are by calendar year, not fiscal year.

Data is grouped by IME lot starting quarter.

Completed IME's only.

IME is B/I 12 hours at 125C and max. op. volt.